

Tutorial 1

1. To describe the binding of two atoms i and j one combines an attractive and a repulsive term to form their total interaction energy.

- a) Discuss possible reasons for attractive and repulsive interaction.
- b) Frequently power terms are assumed for the two interactions:

$$\Phi_{ij}(r_{ij}) = -a/r_{ij}^m + b/r_{ij}^n$$

Show that a bound state is only possible for $n > m$.

- c) Calculate the static lattice energy U_b of a solid in thermal equilibrium at $T = 0$. Use a cubic unit cell and $r_{ij} = p_{ij}r_1$ with r_1 the distance of next neighbours. Then $r_1^3 = V/(2N_p)$ with N_p the number of atom or ion pairs.
 - d) Derive the isothermal compression module $K = -V_0(dp/dV)_T$.
 - e) In an ionic crystal the Coulomb energy forms the attractive part of the interaction energy. Determine U_b , K , n .
 - f) Example NaCl: $\alpha = 1.74$, $K = 3.15 \cdot 10^{10} \text{ N/m}^2$, $r_1 = 2.81 \cdot 10^{-10} \text{ m}$. How large is the lattice energy per ion pair.
2. Madelung constant α_M
 - a) Calculate the Madelung constant for an infinite linear arrangement of positive and negative ions alternating with the distance r_0 .
 - b) Calculate the Madelung constant for a face centered cubic crystal (NaCl). To get a series which converges fast, the ions should be combined to neutral groups in a smart way.

Tutorial 2

3. A metal with cubic structure and one atom per lattice point has density 2.6 g/cm^{-3} , molar mass 87.62 g/mol and lattice constant 0.60849 nm . What is the crystal structure of the metal?
4. Indium has a tetragonal structure with $a = 0.3252 \text{ nm}$ and $c = 0.4946 \text{ nm}$. The density is 7.286 g/cm^{-3} and molar mass 114.82 g/mol . Is the structure simple or body centered tetragonal?
5. What are the Miller indices of a plane through three points with the following coordinates:
 - a) $(0, 0, 1)$; $(1, 0, 0)$; $(1/2, 1/2, 0)$
 - b) $(1, 0, 0)$; $(0, 0, 1/2)$; $(1/2, 1, 0)$
6. The distance d_{hkl} of two parallel net planes (hkl) in a three dimensional orthorhombic system is:

$$d_{hkl}^2 = \frac{1}{(h/a)^2 + (k/b)^2 + (l/c)^2}.$$

Derive the corresponding equation for the two dimensional case ($l = 0$).

7.
 - a) Derive the equilibrium concentration of point vacancies in a solid which can be described by a minimum of the free energy $F = E - TS$. To obtain the entropy $S = k \ln \Omega$ the number Ω of possible distributions of N_L vacancies over N_G lattice places (i.e. the partition function) must be determined. A useful approximation in this derivation is the Stirling formula $\ln n! \approx n \ln n - n$.
 - b) What is the relative concentration of defects N_L/N_G at temperature $T = 1000 \text{ K}$ when the energy to create a vacancy is $E_L = 1 \text{ eV}$?

- c) How precise would one have to measure the density of Si ($\rho = 2.382$ g/cm⁻³, $A_{\text{rel}} = 28.086$) to prove a density of vacancies of 10^{18} cm⁻³?
8. a) A face centered cubic lattice is formed by identical atoms. Which is the condition for h, k, l for a reflex not to be extinguished?
- b) What is the structure factor F_{hkl} of NaCl? NaCl forms a fcc lattice with a base of one Na⁺- and one Cl⁻-Ion.

Tutorial 3

9. How high are the sound velocity and the maximum eigenfrequency of iron atoms in a rod which is stimulated to longitudinal vibrations?
($E = 2 \cdot 10^{11} \text{ N/m}^2$, $a = 2.9 \cdot 10^{-10} \text{ m}$, $M = 55.85 \text{ kg/mol}$, $\rho = 7850 \text{ kg/m}^3$)
10. Under irradiation of a crystal with laser light of vacuum wavelength $\lambda = 488 \text{ nm}$ Raman radiation is observed at $\lambda = 494 \text{ nm}$. What are the energy and frequency of the generated phonons?
11. Compare momentum and energy of a longitudinal acoustic phonon of wavelength $\lambda = 2.6 \text{ nm}$ and circular frequency $\omega = 8.2 \cdot 10^{13} \text{ Hz}$ with these of a photon in the green spectral range ($\lambda = 550 \text{ nm}$).
12. The density of iron is $\rho = 7850 \text{ kg/m}^3$. How high is the Fermi energy E_F under the assumption that every iron atom allocates one free electron to the crystal? How high is the velocity v_F of electrons with states close to the Fermi level?
($M = 55.85 \text{ kg/kmol}$)
13. The Fermi energy of Na is $E_F = 3.1 \text{ eV}$. What are the probabilities that the energy levels $E_1 = 3.05 \text{ eV}$ und $E_2 = 3.15 \text{ eV}$ are occupied at temperatures $T = 300 \text{ K}$ and $T = 600 \text{ K}$, respectively?
How broad is the transition zone ΔE ?

Tutorial 4

14. How high are mobility μ , relaxation time τ and mean free path l of electrons in copper at room temperature?

$$(\sigma = 5.9 \cdot 10^5 \text{ } \Omega^{-1}\text{cm}^{-1}, n = 8.5 \cdot 10^{22} \text{ cm}^{-3})$$

15. Calculate the mean drift velocity of electrons with mobility $\mu = 43 \text{ cm}^2/\text{Vs}$ which are accelerated by a field strength of 100 V/m . Which distance is covered in the direction of the field between two interactions with the crystal lattice at a relaxation time $\tau = 2.5 \cdot 10^{-14} \text{ s}$.

16. What is the specific resistance of pure germanium at $T_1 = 300 \text{ K}$ und $T_2 = 200 \text{ K}$?

$$(n_{i0} = 1.51 \cdot 10^{15} \text{ cm}^{-3}\text{K}^{-1.5}, E_G = 0.66 \text{ eV}, \mu_n(300 \text{ K}) = 3900 \text{ cm}^2\text{V}^{-1}\text{s}^{-1}, \mu_p(300 \text{ K}) = 1900 \text{ cm}^2\text{V}^{-1}\text{s}^{-1})$$

17. Calculate the temperature at which the intrinsic electron concentration of a n-doped silicon sample ($E_G = 1.11 \text{ eV}$) with a phosphorus donor concentration $n_D = 10^{15} \text{ cm}^{-3}$ becomes higher than the concentration of the impurities.

$$(n_{i0} = 4.62 \cdot 10^{15} \text{ cm}^{-3}\text{K}^{-1.5})$$